Low-power dual Schmitt trigger inverter Rev. 8 — 31 January 2022

Product data sheet

1. General description

The 74AUP2G14 is a dual inverter with Schmitt-trigger inputs. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- IOFF circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Low static power consumption; I_{CC} = 0.9 µA (maximum)
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



4. Ordering information

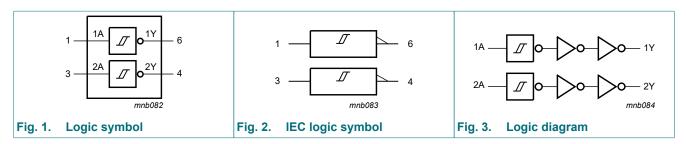
Type number	Package							
	Temperature range Name		Description	Version				
74AUP2G14GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2				
74AUP2G14GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886				
74AUP2G14GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115				
74AUP2G14GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202				
74AUP2G14GX	-40 °C to +125 °C	X2SON6	plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm	SOT1255-2				

5. Marking

Table 2. Marking		
Type number	Marking code[1]	
74AUP2G14GW	рК	
74AUP2G14GM	рК	
74AUP2G14GN	рК	
74AUP2G14GS	рК	
74AUP2G14GX	рК	

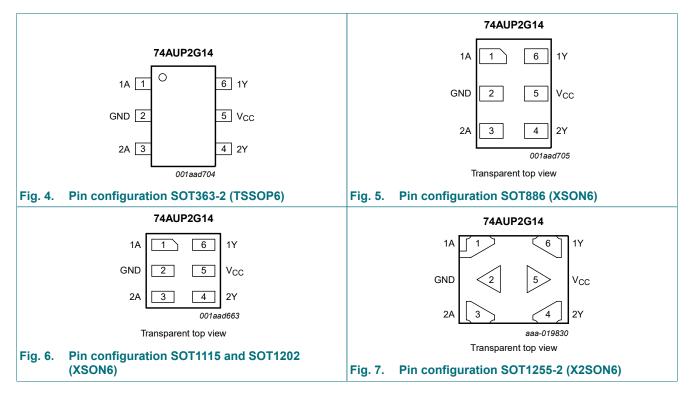
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information





7.2. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
nA	nY
L	Н
Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{ОК}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1255-2 (X2SON6) package: P_{tot} derates linearly with 3.3 mW/K above 75 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	40	μA
Cı	input capacitance	V_1 = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	$\begin{array}{c cccc} - & 0.44 \\ - & 0.31 \\ - & 0.44 \\ - & \pm 0.1 \\ - & \pm 0.2 \\ - & \pm 0.2 \\ - & 0.5 \\ - & 40 \\ \end{array}$		pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
T _{amb} = -4	40 °C to +85 °C VI = VT+ or VT VI = VT+ or VT. VI = 0 = 1.1 mA; VCC = 1.1 V VI = 0 = 0.1 M VI = VT+ or VT. VI = 0 = 1.1 mA; VCC = 1.1 V VI = 0 = 0.1 M VI = 0 = 0.1 M VI = 0 = 0.3 C VI = 0 = 0.1 M VI = 0 = 0.1 M				_{mb} = -40 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}								
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V				
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V				
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V				
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V				
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V				
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V				
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V				
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V				
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}								
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V				
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V				
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V				
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V				
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V				
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V				
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V				
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V				
l _l	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA				
I _{OFF}	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.5	μA				
ΔI _{OFF}			-	-	±0.6	μA				
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μA				
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	50	μA				

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
T _{amb} = -4	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $							
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}						
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V		
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V		
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V		
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V		
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V		
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V		
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V		
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V		
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}						
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V		
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V		
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V		
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V		
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V		
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V		
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V		
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V		
l _l	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA		
I _{OFF}	power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.75	μA		
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	$r_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V;}$					
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	- 1.4			
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	75	μA		

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12. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C			o +85 ℃	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 5 p	F									
t _{pd}	propagation	nA to nY; see <u>Fig. 8</u> [2]								
	delay	V _{CC} = 0.8 V	-	19.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	5.9	11.0	2.4	11.1	2.4	11.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.3	6.6	2.4	7.1	2.4	7.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.7	5.4	2.0	6.0	2.0	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.0	4.1	1.7	4.5	1.7	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.8	3.6	1.5	3.9	1.5	4.0	ns
C _L = 10	pF									
t _{pd}	propagation	nA to nY; see <u>Fig. 8</u> [2]								
	delay	V _{CC} = 0.8 V	-	23.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.8	12.7	2.8	12.8	2.8	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.0	7.7	2.6	8.2	2.6	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	4.2	6.2	2.5	6.7	2.5	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.6	4.8	2.1	5.2	2.1	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.3	4.3	2.0	4.5	2.0	4.7	ns
C _L = 15	pF									
t _{pd}	propagation	nA to nY; see <u>Fig. 8</u> [2]								
	delay	V _{CC} = 0.8 V	-	26.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	7.6	14.3	3.0	14.5	3.0	14.7	ns
		V _{CC} = 1.4 V to 1.6 V	3.3	5.5	8.6	2.9	9.4	2.9	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.8	4.7	7.0	2.8	7.7	2.8	8.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.0	5.5	2.4	5.9	2.4	6.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	3.8	4.8	2.2	5.2	2.2	5.4	ns
C _L = 30	pF									
t _{pd}	propagation	nA to nY; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	37.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	9.8	18.7	3.9	19.6	3.9	20.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.7	7.1	11.2	3.8	12.3	3.8	12.9	ns
		V _{CC} = 1.65 V to 1.95 V	3.6	6.0	9.1	3.6	10.0	3.6	10.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.5	5.2	6.9	3.2	7.5	3.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	4.8	6.1	3.1	7.1	3.1	7.4	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	1
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF								
C _{PD}	power dissipation	$f_i = 1 \text{ MHz};$ [3][4 V _I = GND to V _{CC}]							
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.3	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

 t_{pd} is the same as t_{PLH} and t_{PHL} . [2]

[3] All specified values are the average typical values over all stated loads.

 C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where: [4]

 f_i = input frequency in MHz;

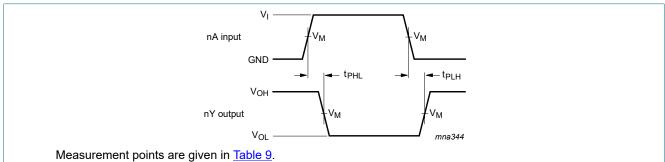
fo = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

12.1. Waveform and test circuit



Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

The data input (nA) to output (nY) propagation delays Fig. 8.

Table 9. Measurement points

Supply voltage	Output	Input				
V _{cc}	V _M	V _M	VI	t _r = t _f		
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns		

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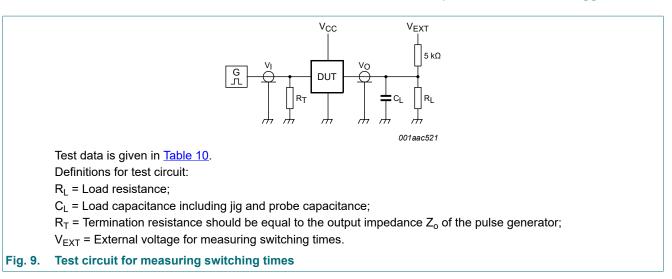


Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, set-up and hold times and pulse width R_L = 1 $M\Omega.$

13. Transfer characteristics

Table 11. Transfer characteristics

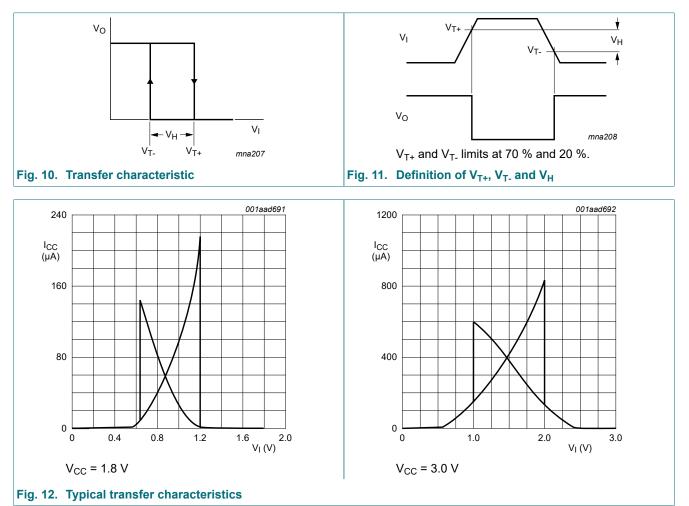
Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9.

Symbol	Parameter	r Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Мах	Min	Max	Min	Max	1
V _{T+}	V _{T+} positive-going	see <u>Fig. 10</u> and <u>Fig. 11</u>								
	threshold voltage	V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	V _{T-} negative-going	see <u>Fig. 10</u> and <u>Fig. 11</u>								
	threshold voltage	V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	voltage	V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V

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Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Мах	
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 10</u> , <u>Fig. 11</u> and <u>Fig. 12</u> .								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

13.1. Waveforms transfer characteristics



14. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = rise time (ns); 10 % to 90 %;
- t_f = fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 13.

An example of a relaxation circuit using the 74AUP2G14 is shown in Fig. 14.

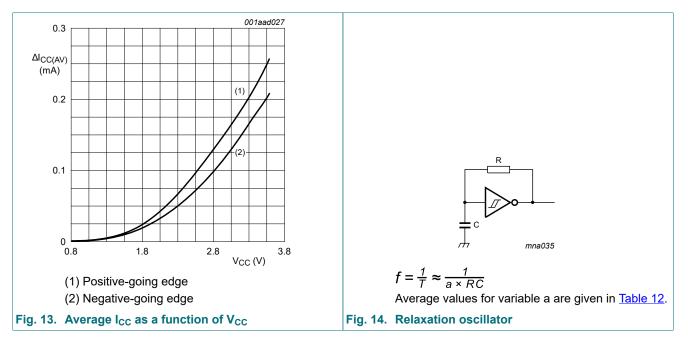


Table 12. Variable values

Supply voltage	Variable a
1.1 V	1.28
1.5 V	1.22
1.8 V	1.24
2.8 V	1.34
3.3 V	1.45

15. Package outline

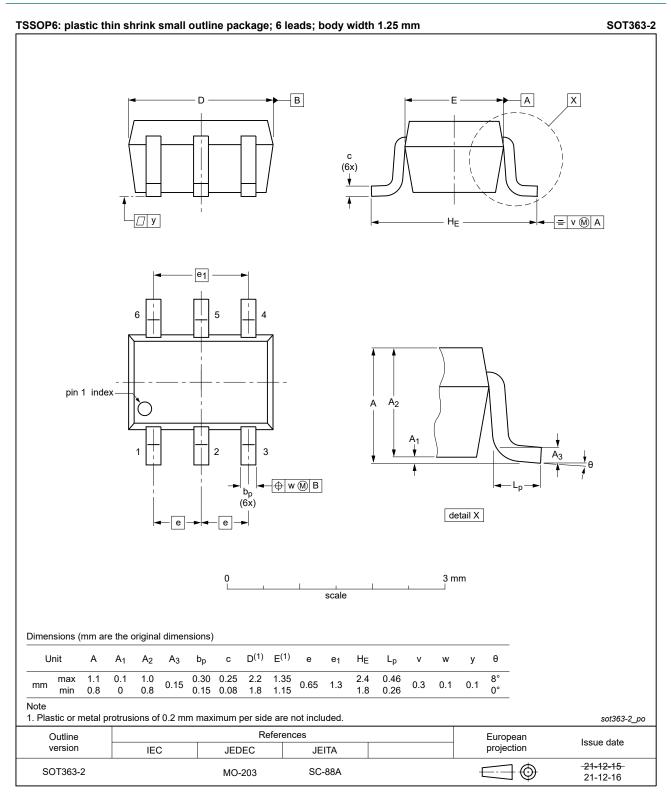


Fig. 15. Package outline SOT363-2 (TSSOP6)

Low-power dual Schmitt trigger inverter

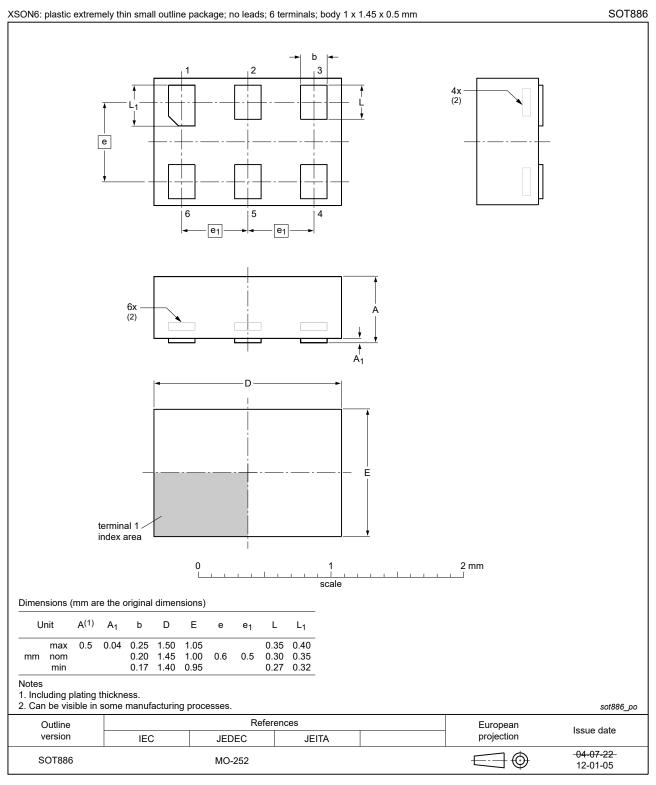
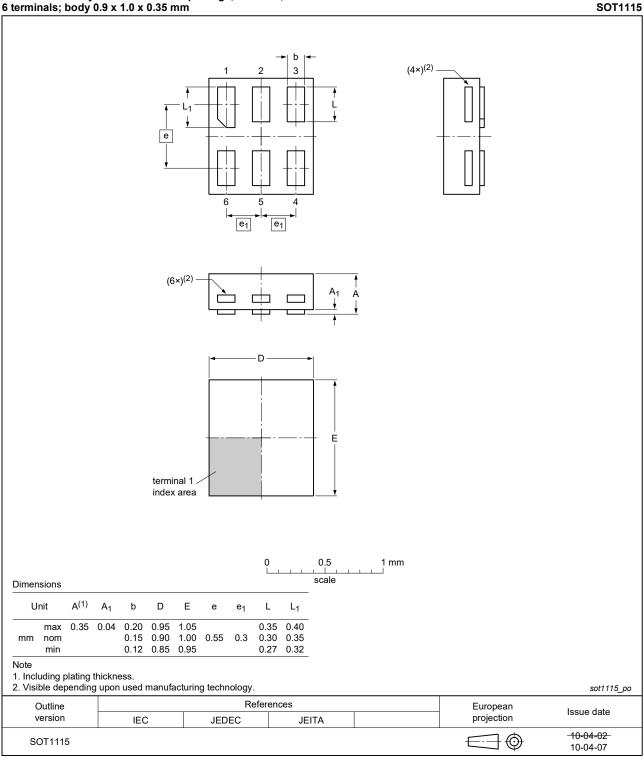


Fig. 16. Package outline SOT886 (XSON6)

Low-power dual Schmitt trigger inverter

XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm





74AUP2G14

Low-power dual Schmitt trigger inverter

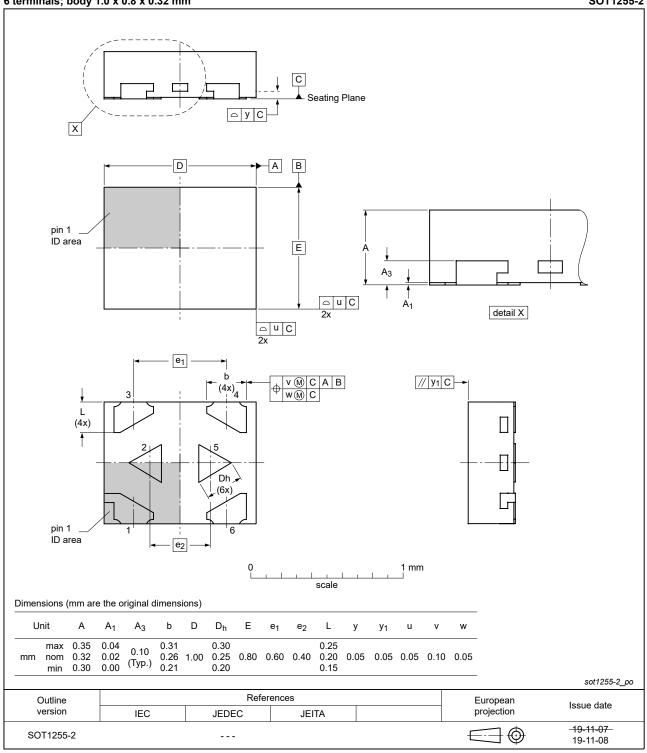
terminals; body 1	thin small outline package; no leads; .0 x 1.0 x 0.35 mm	SOT12
	$ \begin{array}{c} $	
	$(6\times)^{(2)}$	
	terminal 1 index area	
Dimensions	0 0.5 1 mm scale	
Unit A ⁽¹⁾ max 0.35 mm nom min		
Note 1. Including plating th		sot1202_p
Outline	References European	Issue date
version SOT1202	IEC JEDEC JEITA projection	10.04.02

Fig. 18. Package outline SOT1202 (XSON6)

Low-power dual Schmitt trigger inverter

X2SON6: plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 x 0.8 x 0.32 mm

SOT1255-2





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16. Abbreviations

Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			
MM	Machine Model			

17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G14 v.8	20220131	Product data sheet	-	74AUP2G14 v.7
Modifications:	Package SO	T363 (SC-88) changed to S	SOT363-2 (TSSOP6).	
74AUP2G14 v.7	20210705	Product data sheet	-	74AUP2G14 v.6
Modifications:	SOT1255 (XType numbe	d <u>Section 2</u> updated. 2SON6) package changed r 74AUP2G14GF (SOT891 ating values for P _{tot} total po	/XSON6) removed.	, c
74AUP2G14 v.6	20150917	Product data sheet	-	74AUP2G14 v.5
Modifications:	Added type r	number 74AUP2G14GX (S	OT1255/X2SON6).	·
74AUP2G14 v.5	20121204	Product data sheet	-	74AUP2G14 v.4
Modifications:	Package out	line drawing of SOT886 (Fi	ig. <u>16</u>) modified.	
74AUP2G14 v.4	20111201	Product data sheet	-	74AUP2G14 v.3
74AUP2G14 v.3	20100722	Product data sheet	-	74AUP2G14 v.2
74AUP2G14 v.2	20090703	Product data sheet	-	74AUP2G14 v.1
74AUP2G14 v.1	20061219	Product data sheet	_	-

18. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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